DMC50101

Silicon NPN epitaxial planar type

For general amplification DMC20101 in SMini5 type package

■ Features

- \bullet High forward current transfer ratio h_{FE} with excellent linearity
- \bullet Low collector-emitter saturation voltage $V_{\text{CE}(\text{sat})}$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

■ Marking Symbol: A1

■ Basic Part Number

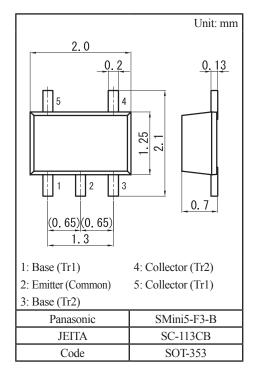
Dual DSC2001 (Common emitter)

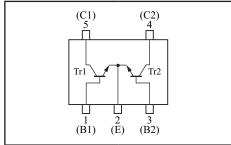
Packaging

DMC501010R Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

| | Parameter | Symbol | Rating | Unit |
|------------|---------------------------------------|------------------|-------------|------|
| Tr1 Tr2 | Collector-base voltage (Emitter open) | V _{CBO} | 60 | V |
| | Collector-emitter voltage (Base open) | V _{CEO} | 50 | V |
| | Emitter-base voltage (Collector open) | V _{EBO} | 7 | V |
| | Collector current | I_{C} | 100 | mA |
| | Peak collector current | I_{CP} | 200 | mA |
| Overall | Total power dissipation | P _T | 150 | mW |
| | Junction temperature | T _j | 150 | °C |
| | Operating ambient temperature | T _{opr} | -40 to +85 | °C |
| | Storage temperature | T _{stg} | -55 to +150 | °C |





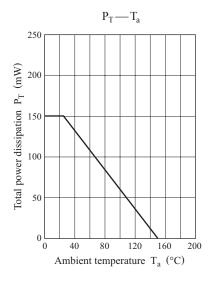
■ Electrical Characteristics $T_a = 25$ °C±3°C

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|-------------------------------|---|------|------|-----|------|
| Collector-base voltage (Emitter open) | V _{CBO} | $I_{\rm C} = 10 \mu \text{A}, I_{\rm E} = 0$ | 60 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$ | 50 | | | V |
| Emitter-base voltage (Collector open) | V_{EBO} | $I_E = 10 \mu A, I_C = 0$ | 7 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = 20 \text{ V}, I_{E} = 0$ | | | 0.1 | μΑ |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = 10 \text{ V}, I_{B} = 0$ | | | 100 | μΑ |
| Forward current transfer ratio | h _{FE} | $V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$ | 210 | | 460 | _ |
| h _{FE} ratio *1 | h _{FE} (Small/Large) | $V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$ | 0.50 | 0.99 | | _ |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ | | 0.13 | 0.3 | V |
| Transition frequency | f_T | $V_{CE} = 10 \text{ V}, I_{C} = 2 \text{ mA}$ | | 150 | | MHz |
| Collector output capacitance (Common base, input open circuited) | C _{ob} | $V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ | | 1.5 | | pF |

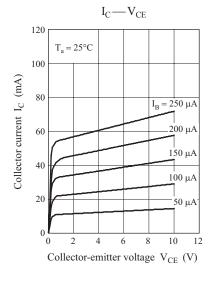
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

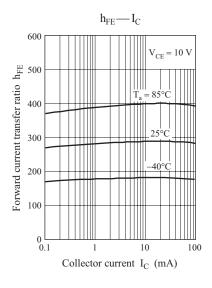
2. *1: Ratio between 2 elements

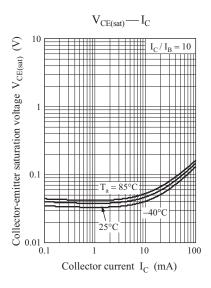
Panasonic

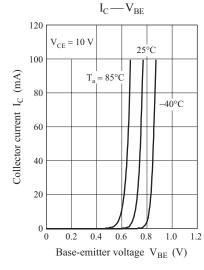


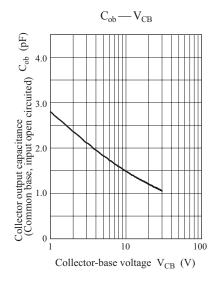
DMC50101

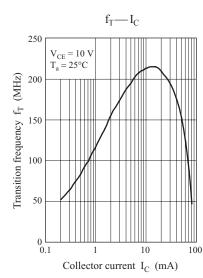








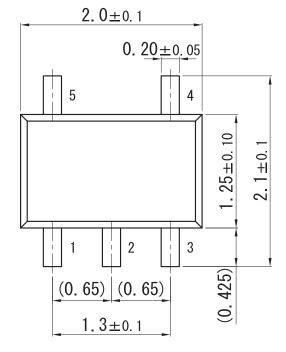


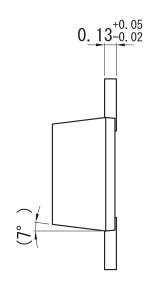


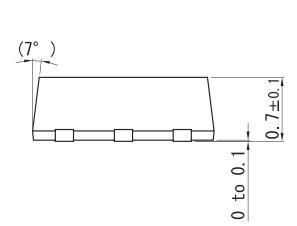
Ver. FED 2

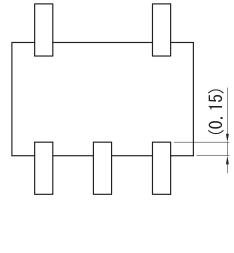
SMini5-F3-B

Unit: mm

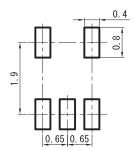








■ Land Pattern (Reference) (Unit: mm)



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